Hardware Development Guide for the MIMXRT1050 Processor

1. Introduction

This document's purpose is to help hardware engineers design and test their MIMXRT1050 processor-based designs. It provides information about board layout recommendations and design checklists to ensure first-pass success and avoidance of board bring-up problems.

This guide is released along with the relevant device-specific hardware documentation such as data sheets, reference manuals, and application notes available on nxp.com.

2. Background

The MIMXRT1050 processors are NXP's latest additions to a growing family of real-time processing products, offering high-performance processing optimized for lowest power consumption and best real-time response. The MIMXRT1050 processors feature NXP's advanced implementation of the Arm® Cortex[®]-M7 core which operates at speeds of up to 600 MHz. The MIMXRT1050 processors are specifically useful for applications such as:

- Industrial Human Machine Interfaces (HMI)
- Motor control
- Home appliances

Contents

1.	Intro	duction	1
2.	Back	ground]
3.	Pow	er supply	2
4.		ks	
5.	Deb	ugging and programming	
6.	Boo	t, reset, and miscellaneous	9
7.		out recommendations	
	7.1.		
	7.2.	Placement of bulk and decoupling capacitors	13
	7.3.	SDRAM	14
	7.4.	USB	14
	7.5.	High-speed signal routing recommendations	15
8.	Revi	sion history	



2

3. Power supply

See Table 1 for the power domains and power supply decoupling recommendations. Note that the power control diagram (described in RT1050-EVK) is applicable to A0 silicon. For A1 silicon, DCDC_IN is expected to be powered by the other domains together.

Table 1. Power domains

Power rail	MIN (V)	TYP (V)	MAX (V)	Description		
VDD_SOC_IN	0.925	_	1.26	Power for the core supply		
VDD_HIGH_IN	3	3.3	3.6	VDD_HIGH_IN supply voltage		
DCDC_IN	2.8 ¹	2.9 ¹	3.0 ¹	Power for the DCDC		
VDD_SNVS_IN	2.4	3	3.6	Power for the SNVS and RTC		
USB_OTG1_VBUS USB_OTG2_VBUS	4.4	5	5.5	Power for the USB VBUS		
VDDA_ADC	3	3.3	3.6	Power for the 12-bit ADC		
VDDA_IN	3	3.3	3.6	Power for the 12-bit ADC		
NIVOO ODO	3	3.3	3.6	Power for the GPIO in the SDIO1 bank (3.3 V mode)		
NVCC_SD0	1.65	1.8	1.95	Power for the GPIO in the SDIO1 bank (1.8 V mode)		
NIVOC SD4	3	3.3	3.6	Power for the GPIO in the SDIO2 bank (3.3 V mode)		
NVCC_SD1	1.65	1.8	1.95	Power for the GPIO in the SDIO2 bank (1.8 V mode)		
NIVOO EMO	3	3.3	3.6	IO supply for the GPIO in the EMC bank (3.3 V mode)		
NVCC_EMC	1.65	1.8	1.95	IO supply for the GPIO in the EMC bank (1.8 V mode)		
NVCC_GPIO	3	3.3	3.6	IO power for the GPIO		

^{1.} For A0 silicon, the DCDC_IN voltage domain is 2.8 V ~ 3.0 V, while for A1 silicon and the later DCDC_IN, the voltage domain is 3.0 V~3.6 V.

Table 2. Power supply decoupling recommendations

Power rail	Decoupling and bulk capacitors (min qty)	Description
VDD_SOC_IN	5 × 0.22 μF² + 1 × 4.7 μF¹ + 1 × 22 μF³	Place at least one 4.7 μF capacitor and three 0.22 μF capacitors next to balls F6, F7, F8, and so on.
VDD_HIGH_IN	$1 \times 0.22 \ \mu F^2 + 1 \times 4.7 \ \mu F^1$	_
VDD_HIGH_CAP	1 × 0.22 μF² + 1 × 4.7 μF¹	VDDHIGH_CAP is restricted to the MX6RT loads.
DCDC_IN	$3 \times 0.22 \ \mu\text{F}^2 + 1 \times 4.7 \ \mu\text{F}^1 + 1 \times 22 \ \mu\text{F}^3$	Place at least one 4.7 μF capacitor and one 0.22 μF capacitor next to ball M1.
VDD_SNVS_IN	1 × 0.22 μF²	_
VDD_SNVS_CAP	1 × 0.22 μF² + 1 × 4.7 μF¹	Select a small capacitor with a low ESR. Do not connect any loads to VDD_SNVS_CAP.
USB_OTG1_VBUS USB_OTG2_VBUS	1 × 1 μF¹	10-V rated.
VDDA_ADC_3P3	1 × 0.22 μF² + 1 × 1 μF¹	Place the buck and bypass capacitors next to ball N14.
NVCC_SD0	1 × 0.1 μF + 1 × 4.7 μF¹	Place the buck and bypass capacitors next to ball J6.
NVCC_SD1	1 × 0.1 μF + 1 × 4.7 μF¹	Place the buck and bypass capacitors next to ball K5.
NVCC_EMC	2 × 0.1 μF + 1 × 4.7 μF¹	Place the buck and bypass capacitors next to balls F5 and E6.
NVCC_GPIO	$3 \times 0.1 \mu\text{F} + 1 \times 4.7 \mu\text{F}^{1}$	_

For the 4.7-μF capacitors, use the 0402 package.
 For the 0.22-μF capacitors, use the 0402 package.
 For the 22-μF capacitors, the 0603 package is preferred; the 0805 and 1206 packages are acceptable.

Table 3. Power sequence and recommendations

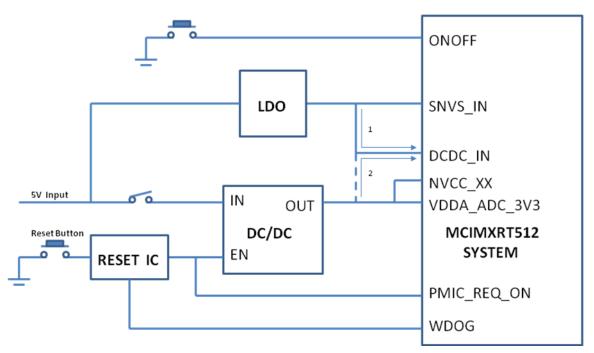
Item	Recommendation	Description
1. Power sequence	Comply with the power-up/power-down sequence guidelines (as described in the data sheet) to guarantee a reliable operation of the device.	Any deviation from these sequences may result in these situations: • Excessive current during the power-up phase • Prevention of the device from booting • Irreversible damage to the processor (worst-case scenario)
2. SNVS domain signals	Do not overload the coin cell backup power rail VDD_SNVS_IN. Note that these I/Os are associated with VDD_SNVS_IN (most inputs have on-chip pull resistors and do not require external resistors): • PMIC_STBY_REQ—configurable output • PMIC_ON_REQ—push-pull output • TEST_MODE—on-chip pulldown • WAKEUP—the GPIO that wakes the SoC up in the SNVS mode	Concerning i.MX RT1050: • When VDD_SNVS_IN = VDD_HIGH_IN in the SNVS domain, the current is drawn from both equally. • When VDD_HIGH_IN > VDD_SNVS_IN, VDD_HIGH_IN supplies all the SNVS domain current and the current flows into VDD_SNVS_IN to charge the coin cell battery. • When VDD_SNVS_IN > VDD_HIGH_IN, VDD_SNVS_IN supplies current to SNVS, and a small leakage current flows into VDD_HIGH_IN.
3. Power ripple	Maximum ripple voltage limitation.	The common limitation for the ripple noise shall be less than 5 % Vp-p of the supply voltage average value. The related power rails affected are VDD_xxx_IN and VDD_xxx_CAP. Note that for DCDC_IN, the ripple is within 1 % for A0 silicon.
4. VDD_SNVS_IN and VDD_HIGH_IN	If VDD_SNVS_IN is directly supplied by a coin cell battery, a schottky diode is required between VDD_HIGH_IN and VDD_SNVS_IN. The cathode is connected to VDD_SNVS_IN. Alternately, VDD_HIGH_IN and VDD_SNVS_IN can be tied together if the real-time clock function is not needed during the system power-down.	When no power is supplied to VDD_VSNVS_IN, the diode limits the voltage difference between the two on-chip SNVS power domains to approximately 0.3 V. The processor allows the current to flow between the two SNVS power domains, proportionally to the voltage difference.

For RT1050-EVK, see Figure 1.

- Firstly, it powers up SNVS and DCDC_IN together. PMIC_REQ_ON is then switched on to enable the external DC/DC to power up other power domains.
- The ON/OFF button is used to switch PMIC_REQ_ON on/off to control power modes.
- The RESET button and the WDOG output are used to reset the system power.

NOTE

For silicon A0 silicon, follow the above power logic. If you don't power SNVS together with DCDC_IN by 2.8 V \sim 3.0 V, the on-chip DCDC module does not work properly. For silicon A1 silicon (and later), this issue is fixed and you can power DCDC_IN using an external DC/DC with a voltage of 3.0 V \sim 3.6 V.



- 1. For A0 silicon, DCDC_IN and SNVS_IN are powered by an external LDO.
- 2. For A1 silicon, DCDC_IN, NVCC_XX, and VDDA_ADC_3V3 are powered by an external DC/DC.

Figure 1. Power control diagram

4. Clocks

See Table 4 for the clock configuration. The 32.768-kHz and 24-MHz oscillators are used for the EVK design.

Signal name Description Recommended connections i. MX 6 Series Processor Internal Oscillation Oscillator **Amplifier** Sensing Internal Amplifier Circuitry To hit the exact oscillation Rbias frequency, the board capacitors Automatic must be reduced to account for the board and chip parasitics. The Solder bump Solder bump RTC_XTALI RTC XTALO integrated oscillation amplifier is self-biasing, but relatively weak. Care must be taken to limit the parasitic leakage from RTC_XTALI and RTC_XTALO to either the power or the ground (>100 M). This de-biases the amplifier and reduces For the precision 32.768-kHz oscillator, connect a the start-up margin. crystal between RTC_XTALI and RTC_XTALO. Choose a crystal with a maximum ESR (Equivalent Series Resistance) of 100 k and follow the manufacturer's recommendation for the loading capacitance. Do not use an external biasing resistor because the bias circuit is on 1.RTC_XTALI/RTC_XTALO the chip. If you want to feed an external low-frequency clock into RTC_XTALI, the RTC_XTALO pin For the external kHz source (if feeding an external clock must remain unconnected or driven into the device), RTC_XTALI can be driven DC-coupled by a complementary signal. The with RTC_XTALO floating or driven by a complimentary logic level of this forcing clock signal. must not exceed the VDD_SNVS_CAP level and the frequency shall be <100 kHz under the typical conditions. When a high-accuracy real-time clock is not required, the system may use the on-chip 40-kHz oscillator. The tolerance is ±50 %. An on-chip loose-tolerance ring oscillator of The ring oscillator starts faster than approximately 40 kHz is available. If RTC_XTALI is tied the external crystal and is used until to GND and RTC_XTALO is floating, the on-chip the external crystal reaches a oscillator is engaged automatically. stable oscillation. The ring oscillator also starts automatically if no clock is detected at RTC_XTALI at any The SDK software requires 24 MHz on XTALI/XTALO. The crystal can be eliminated if an For the precision 24-MHz oscillator, connect a external 24-MHz oscillator is fundamental-mode crystal between XTALI and XTALO. available in the system. In this An typical 80 ESR crystal rated for a maximum drive 2. XTALI/XTALO case, XTALO must be directly level of 250 µW is acceptable. driven by the external oscillator and Alternately, a typical 50 ESR crystal rated for a XTALI must be mounted with a maximum drive level of 200 µW may be used. 18-pF capacitor. The logic level of this forcing clock must not exceed the NVCC_PLL level.

Table 4. Clocks' configurations

Clocks' configurations Table 4.

Signal name	Recommended connections	Description
		If this clock is used as a reference for the USB, then there are strict frequency tolerance and jitter requirements. See the OSC24M chapter and the relevant interface specifications chapters for details.
	Bias XTALI with a 2.2-M resistor to GND. Mount the resistor close to the XTALI ball.	The XTALI bias must be adjusted externally to ensure a reasonable start-up time.
3.CCM_CLK1_P/ CCM_CLK1_N	One general-purpose differential high-speed clock input/output (LVDS I/O) is provided. It can be used: • To feed the external reference clock to the PLLs and further to the modules inside the SoC. • To output the internal SoC clock to be used outside the SoC as either a reference clock or a functional clock for the peripherals.	See the i.MX RT1050 Reference Manual for details about the respective clock trees. Alternatively, use a single-ended signal to drive the CLK1_P input. In this case, the corresponding CLK1_N input must be tied to a constant voltage level equal to one half of the input signal swing. The termination must be provided in case of high-frequency signals. After the initialization, the CLK1 input/output can be disabled (if not used). If not used, either one or both CLK1_N/P pairs may remain unconnected.

5. Debugging and programming

See Table 5 for the JTAG interface summary and recommendation. The RT1050 EVK also features an OpenSDA, which makes it easier to debug without an external debugger.

Table 5. JTAG interface summary

JTAG signals	I/O type	On-chip termination	External termination
JTAG_TCK	Input	47 kΩ pull-up	Not required; can use 10 kΩ pull-up
JTAG_TMS	Input	47 kΩ pull-up	Not required; can use 10 kΩ pull-up
JTAG_TDI	Input	47 kΩ pull-up	Not required; can use 10 kΩ pull-up
JTAG_TDO	3-state output	100 kΩ pull-up	Do not use pullup or pull-down
JTAG_TRSTB	Input	47 kΩ pull-up	Not required; can use 10 kΩ pull-up
JTAG_MOD	Input	100 kΩ pull-up	Use 4.7 kΩ pull-down or tie to GND

Debugging and programming

8

Table 6. JTAG recommendation

Signals	Recommendation	Description	
1. JTAG_TDO	Do not add external pull-up or pull-down resistors on JTAG_TDO.	JTAG_TDO is configured with an on-chip keeper circuit, such that the floating condition is actively eliminated if an external pull resistor is not present. An external pull resistor on JTAG_TDO is detrimental. See Table 5 for a summary of the JTAG interface.	
2. JTAG_TDO	Ensure that the on-chip pull-up/pull-down configuration is followed if external resistors are used with the JTAG signals (except for JTAG_TDO). For example, do not use an external pull-down on an input that has an on-chip pull-up.	External resistors can be used with all JTAG signals except for JTAG_TDO, but they are not required. See Table 5 for a summary of the JTAG interface.	
3. JTAG_MOD	JTAG_MOD is called SJC_MOD in some documents. Both names refer to the same signal. JTAG_MOD shall be externally connected to GND for normal operation in a system. The termination to GND through an external pull-down resistor is allowed. Use a 4.7-kΩ resistor.	When JTAG_MOD is low, the JTAG interface is configured for a common software debug, adding all the system TAPs to the chain. When JTAG_MOD is high, the JTAG interface is configured to a mode compliant with the IEEE 1149.1 standard.	

Table 7. OpenSDA recommendation

Signals	Recommendation	Description	
1. SWD_DIO	Connect to the K20 signal through a buffer	The OpenSDA in the EVK board is	
2. SWD_CLK	Connect to the K20 signal through a buffer	implemented as a debugger, which eliminates the cost for the users.	
3.UART_TXD/UART_RXD	Connect to the K20 signal through a buffer	The UART signals connected to K20 realize a virtual COM port for the OpenSDA USB for debugging.	

Table 8. Flashloader peripheral I/Os

Table of Traditional Portprioral #00					
Signals	Recommendation	Description			
1.UART1	The Serial Downloader provides a means to download a program image to the chip over the USB and UART serial connections. In this mode, ROM programs WDOG1 for a time-out specified by the fuse WDOG Time-out Select (See the Fusemap chapter for details) if the WDOG ENABLE eFuse is 1	The ROM code firstly polls the UART1 signals from TXD1/RXD1. Add a 10-kΩ pull up resistor to the TXD1/RXD1 pins to avoid an invalid trigger of the UART port in the serial download mode.			
2. USB1	and continuously polls for the USB and UART connection. If no activity is found on USB OTG1 and UART 1/2 and the watchdog timer expires, the Arm core is reset.	If there is no polling activity from UART1 in the serial download mode, the ROM code acts as an HID device for PC downloading.			

6. Boot, reset, and miscellaneous

See Table 9 for the boot, reset, and miscellaneous configurations, such as ON/OFF, TEST_MODE, NC pins, and other.

Table 9. Boot configuration

Item	Recommendation	Description
1. BOOT_CFG[11:0]	The BOOT_CFG signals are required for a proper functionality and operation and shall not be left floating.	See the "System Boot" chapter in your chip reference manual for the correct boot configuration. Note that an incorrect setting may result in an improper boot sequence.
2. BOOT_MODE[1:0]	For BOOT_MODE1 and BOOT_MODE0, use one of these options to achieve logic 0: • Tie to GND through any-value external resistor • Tie directly to GND For logic 1, use one of these options: • Tie directly to the NVCC_GPIO_XX rail • Tie to the NVCC_GPIO_XX rail through an external 10-kΩ resistor. A value of 4.7 kΩ is preferred for high-noise environments. If a switch control is desired, no external pull-down resistors are necessary. Simply connect the SPST switches directly to the NVCC_GPIO_XX rail.	BOOT_MODE1 and BOOT_MODE0 each have on-chip pull-down devices with a nominal value of $100~\text{k}\Omega$, a projected minimum of $60~\text{k}\Omega$, and a projected maximum of $140~\text{k}\Omega$. When the on-chip fuses determine the boot configuration, both boot mode inputs can be disconnected.
3. BOOT_CFG and BOOT_MODE signals multiplexed with LCD signals	To reduce incorrect boot-up mode selections, do one of the following: • Use the LCD boot interface lines only as processes or outputs. Make sure that the LCD boot interface lines are not loaded down (such that the level is interpreted as low during the powerup) when the intent is to be at a high level, or the other way round. • If the LCD boot signal must be configured as an input, isolate the LCD signal from the target driving source with an analog switch and apply the logic value with a second analog switch. Alternately, the peripheral devices with 3-state outputs may be used. Ensure that the output is high-impedance.	Using the LCD boot interface lines as inputs may result in a wrong boot because of the source overcoming the pull resistor value. A peripheral device may require the LCD signal to have an external or on-chip resistor to minimize signal floating. If the usage of the LC boot signal affects the peripheral device, then an analog switch, an open collector buffer, or an equivalent shall isolate the path. A pull-up or pull-down resistor at the peripheral device may be required to maintain the desired logic level. See the switch or device data sheet for the operating specifications.

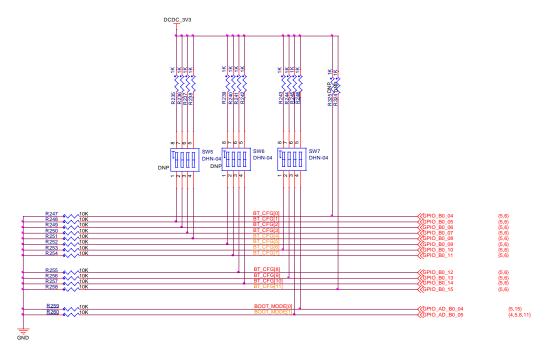


Figure 2. Boot mode setting

Table 10. Reset and miscellaneous recommendations

Item	Recommendation	Description	
1. POR_B	If the external POR_B signal is used to control the processor POR, then POR_B must be immediately asserted at the powerup and remain asserted until the VDD_HIGH_CAP and VDD_SNVS_CAP supplies are stable. VDD_SOC_IN may be applied in either order with no restrictions. In the absence of an external reset feeding the SRC_POR_B input, the internal POR module takes control.	See the "System Boot" chapter in your chip reference manual for the correct boot configuration. Note that an incorrect setting may result from an improper boot sequence.	
2. ON/OFF	For portable applications, the ON/OFF input may be connected to the ON/OFF SPST push-button. The on-chip debouncing is provided, and this input has an on-chip pullup. If not used, ON/OFF can be a no-connect. A 4.7-k Ω to 10-k Ω series resistor can be used when the current drain is critical.	A brief connection to GND in the OFF mode causes the internal power management state machine to change the state to ON. In the ON mode, a brief connection to GND generates an interrupt (intended to be a software-controllable power-down). Approximately five seconds (or more) to GND causes a forced OFF. Both boot mode inputs can be disconnected.	
3. TEST_MODE	The TEST_MODE input is internally connected to an on-chip pull-down device. You may either float this signal or tie it to GND.	This input is reserved for NXP manufacturing use.	
4. GPANAIO	GPANAIO must be a no-connect.	This output is reserved for NXP manufacturing use.	
5. NC pin	The NC contacts are no-connect and shall float.	Depending on the feature set, some versions of ICs may have the NC contacts connected inside the BGA.	

Hardware Development Guide for the MIMXRT1050 Applications Processor, Rev.1, 11/2017

Table 11. ROM Bootloader Peripheral PinMux

Peripheral	Instance	Port (IO function)	PAD	Mode
-		LPUART1_TX	GPIO_AD_B0_12	ALT2
LPUART	1	LPUART1_RX	GPIO_AD_B0_12	ALT2
		LPSPI1_SCK	GPIO_XD_B0_10	ALT4
		LPSPI1_SDO	GPIO_SD_B0_02	ALT4
	1	LPSPI1_SDI	GPIO_SD_B0_03	ALT4
		LPSPI1_PCS0	GPIO_SD_B0_01	ALT4
		LPSPI2_SCK	GPIO_SD_B1_07	ALT4
		LPSPI2_SDO	GPIO_SD_B1_08	ALT4
	2	LPSPI2_SDI	GPIO_SD_B1_09	ALT4
		LPSPI2_PCS0	GPIO_SD_B1_06	ALT4
LPSPI		LPSPI3_SCK	GPIO_AD_B0_00	ALT7
		LPSPI3_SDO	GPIO_AD_B0_01	ALT7
	3	LPSPI3_SDI	GPIO_AD_B0_02	ALT7
		LPSPI3_PCS0	GPIO_AD_B0_03	ALT7
		LPSPI4_SCK	GPIO_B0_03	ALT3
		LPSPI4_SDO	GPIO_B0_02	ALT3
	4	LPSPI4_SDI	GPIO_B0_01	ALT3
		LPSPI4_PCS0	GPIO_B0_00	ALT3
		SEMC_DATA00	GPIO_EMC_00	ALT0
		SEMC_DATA01	GPIO_EMC_01	ALT0
		SEMC_DATA02	GPIO_EMC_02	ALT0
		SEMC_DATA03	GPIO_EMC_03	ALT0
		SEMC_DATA04	GPIO_EMC_04	ALT0
		SEMC_DATA05	GPIO_EMC_05	ALT0
		SEMC_DATA06	GPIO_EMC_06	ALT0
		SEMC_DATA07	GPIO_EMC_07	ALT0
		SEMC_DATA08	GPIO_EMC_30	ALT0
		SEMC_DATA09	GPIO_EMC_31	ALT0
SEMC NAND	_	SEMC_DATA10	GPIO_EMC_32	ALT0
		SEMC_DATA11	GPIO_EMC_33	ALT0
		SEMC_DATA12	GPIO_EMC_34	ALT0
		SEMC_DATA13	GPIO_EMC_35	ALT0
		SEMC_DATA14	GPIO_EMC_36	ALT0
		SEMC_DATA15	GPIO_EMC_37	ALT0
		SEMC_ADDR9	GPIO_EMC_18	ALT0
		SEMC_ADDR11	GPIO_EMC_19	ALT0
		SEMC_ADDR12	GPIO_EMC_20	ALT0
		SEMC_BA1	GPIO_EMC_22	ALT0
		SEMC_CSX0	GPIO_EMC_41	ALT0
		SEMC_DATA00	GPIO_EMC_00	ALT0
		SEMC_DATA01	GPIO_EMC_01	ALT0
		SEMC_DATA02	GPIO_EMC_02	ALT0
		SEMC_DATA03	GPIO_EMC_03	ALT0
		SEMC_DATA04	GPIO_EMC_04	ALT0
		SEMC_DATA05	GPIO_EMC_05	ALT0
SEMC NOR	_	SEMC_DATA06	GPIO_EMC_06	ALT0
223 7,010		SEMC_DATA07	GPIO_EMC_07	ALT0
		SEMC_DATA08	GPIO_EMC_30	ALT0
		SEMC_DATA09	GPIO_EMC_31	ALT0
		SEMC_DATA10	GPIO_EMC_32	ALT0
		SEMC_DATA11	GPIO_EMC_33	ALTO
		SEMC_DATA12	GPIO_EMC_34	ALT0
		SEMC_DATA13	GPIO_EMC_35	ALT0

Table 11. ROM Bootloader Peripheral PinMux

Peripheral	Instance	Port (IO function)	PAD	Mode
		SEMC_DATA14	GPIO_EMC_36	ALT0
		SEMC_DATA15	GPIO_EMC_37	ALT0
		SEMC_ADDR0	GPIO_EMC_09	ALT0
		SEMC_ADDR1	GPIO_EMC_10	ALT0
		SEMC_ADDR2	GPIO_EMC_11	ALT0
		SEMC_ADDR3	GPIO_EMC_12	ALT0
		SEMC_ADDR4	GPIO_EMC_13	ALT0
		SEMC_ADDR5	GPIO_EMC_14	ALT0
		SEMC_ADDR6	GPIO_EMC_15	ALT0
		SEMC_ADDR7	GPIO_EMC_16	ALT0
		SEMC_ADDR11	GPIO_EMC_19	ALT0
		SEMC_ADDR12	GPIO_EMC_20	ALT0
		SEMC_BA0	GPIO_EMC_21	ALT0
		SEMC_BA1	GPIO_EMC_22	ALT0
		SEMC_CSX0	GPIO_EMC_41	ALT0
		USDHC1_CMD	GPIO_SD_B0_00	ALT0
		USDHC1_CLK	GPIO_SD_B0_01	ALT0
	1	USDHC1_DATA0	GPIO_SD_B0_02	ALT0
	·	USDHC1_DATA1	GPIO_SD_B0_03	ALT0
		USDHC1_DATA2	GPIO_SD_B0_04	ALTO
		USDHC1_DATA3	GPIO_SD_B0_05	ALTO
		USDHC2_DATA3	GPIO_SD_B1_00	ALTO
0.0		USDHC2_DATA2	GPIO_SD_B1_01	ALTO
SD		USDHC2_DATA1	GPIO_SD_B1_02	ALTO
		USDHC2_DATA0	GPIO_SD_B1_03	ALTO
		USDHC2_CLK	GPIO_SD_B1_04	ALTO
	2	USDHC2_CMD	GPIO_SD_B1_05	ALTO
		USDHC2_RESET_B USDHC2_DATA4	GPIO_SD_B1_06 GPIO_SD_B1_08	ALTO ALTO
		USDHC2_DATA4	GPIO_SD_B1_09	ALTO
		USDHC2_DATA6	GPIO_SD_B1_09 GPIO_SD_B1_10	ALTO
		USDHC2_DATA7	GPIO_SD_B1_11	ALTO
		FLEXSPI_B_DATA3	GPIO_SD_B1_11	ALT1
		FLEXSPI_B_DATA2	GPIO_SD_B1_01	ALT1
		FLEXSPI_B_DATA1	GPIO_SD_B1_02	ALT1
		FLEXSPI_B_DATA0	GPIO_SD_B1_03	ALT1
		FLEXSPI_B_SCLK	GPIO_SD_B1_04	ALT1
		FLEXSPI_B_DQS	GPIO_SD_B0_05	ALT4
		FLEXSPI_B_SS0_B	GPIO_SD_B0_04	ALT4
		FLEXSPI_B_SS1_B	GPIO_SD_B0_01	ALT6
	1	FLEXSPI_A_DQS	GPIO_SD_B1_05	ALT1
FlexSPI		FLEXSPI_A_SS0_B	GPIO_SD_B1_06	ALT1
		FLEXSPI_A_SS1_B	GPIO_SD_B0_00	ALT6
		FLEXSPI_A_SCLK	GPIO_SD_B1_07	ALT1
		FLEXSPI_A_DATA0	GPIO_SD_B1_08	ALT1
		FLEXSPI_A_DATA1	GPIO_SD_B1_09	ALT1
		FLEXSPI_A_DATA2	GPIO_SD_B1_10	ALT1
		FLEXSPI_A_DATA3	GPIO_SD_B1_11	ALT1
		FLEXSPI_A_DATA7	GPIO_SD_B1_00	ALT1
		FLEXSPI_A_DATA6	GPIO_SD_B1_01	ALT1
		FLEXSPI_A_DATA5	GPIO_SD_B1_02	ALT1
		FLEXSPI_A_DATA4	GPIO_SD_B1_03	ALT1

7. Layout recommendations

7.1. Stackup

A high-speed design requires a good stackup to have the right impedance for the critical traces.

```
.062" THK +/- 10%

F[N[SHED Cu WEIGHT

LAYER 1 COMPONENT SIDE 1/2az+plating

LAYER 2 GROUND PLANE 1 az.

LAYER 3 POWER PLANE 1 az.

LAYER 4 SOLDER SIDE 1/2az+plating
```

Figure 3. RT1050-EVK stackup

The constraints for the trace width depend on many factors, such as the board stackup and the associated dielectric and copper thickness, required impedance, and required current (for power traces). The stackup also determines the constraints for routing and spacing. Consider the following when designing the stackup and selecting the material for your board:

- The board stackup is critical for the high-speed signal quality.
- Preplan the impedance of the critical traces.
- The high-speed signals must have reference planes on adjacent layers to minimize crosstalk.
- The NXP reference design equals Isola FR4.
- The NXP validation boards equal Isola FR4.
- The recommended stackup is four layers, with the layer stack shown in Figure 3.

The left-hand image shows the detail provided by NXP inside the fabrication detail as a part of the Gerber files. The right-hand side shows the solution suggested by the PCB fabrication company for the requirements. Figure 4 shows the RT1050-EVK PCB stackup implementation:

	Single Ended		Differential		Differential			
Layers	Frace Width (Nils)	Impedance (Ohms	Trace Width (Nils)	Trace Spacing "Airgap" (Nils	Impedance (Ohms	Trace Nidth (Nils)	Trace Spacing 'Airgap' (Mils)	Impedance (Ohms)
LI	5.00	50	4 2	6,00	100	4 70	5,00	90
L4	5.00	50				4 70	5,00	90

Figure 4. RT1050-EVK stackup implementation

7.2. Placement of bulk and decoupling capacitors

Place the small decoupling capacitors and the larger bulk capacitors on the bottom side of the CPU. The 0402 decoupling capacitors and the 0603 bulk capacitors must be placed as close as possible to the power balls. Placing the decoupling capacitors close to the power balls is critical to minimize inductance and ensure the high-speed transient current demand of the processor. The correct via size, trace width,

Hardware Development Guide for the MIMXRT1050 Applications Processor, Rev.1, 11/2017

Layout recommendations

and trace space are critical to preserve the adequate routing space. The recommended geometry is as follows:

- For the BGA constraint area:
 - The via type is 14/8 mils, the trace width is 4 mils, and the trace space is 3.79 mils.
- For the default area (except for the BGA):
 - The via type is 18/8 mils, the trace width is 5 mils, and the trace space is 7 mils.
 - The preferred BGA power-decoupling design layout is available at <u>nxp.com</u>.
 - Use the NXP design strategy for power and decoupling.

7.3. SDRAM

The SDRAM interface (running at up to 166 MHz) is one of the critical interfaces for the chip routing. The controlled impedance for the single-ended traces must be 50 Ω . Ideally, route all signals at the same length as the EVK board. See the RT1050-EVK layout to route all signals at the same length (\pm 50 mils).

The SDRAM routing must be separated into three groups: data, address, and control. See the EVK layout to separate all SDRAM signals into two groups:

- All data lines and DM[x]
- All address lines and control lines

Because the RT1050-EVK is a 4-layer board design, both routing groups refer to the GND plane for the impedance control. One group is routed at the top layer (the reference plane is the second layer), while the other group is routed at the bottom layer (the reference plane is the third layer).

7.4. USB

Use these recommendations for the USB:

- Route the high-speed clocks and the DP and DM differential pair firstly.
- Route the DP and DM signals on the top (or bottom) layer of the board.
- The trace width and spacing of the DP and DM signals must meet the differential impedance requirement of 90 Ω .
- Route the traces over the continuous planes (power and ground):
 - They must not pass over any power/GND plane slots or anti-etch.
 - When placing the connectors, make sure that the ground plane clearouts around each pin have ground continuity between all pins.
- Maintain the parallelism (skew-matched) between DP and DM, and match the overall differential length difference to less than 5 mils.
- Maintain the symmetric routing for each differential pair.
- Do not route the DP and DM traces under the oscillators or parallel to the clock traces (and/or data buses).
- Minimize the lengths of the high-speed signals that run parallel to the DP and DM pair.
- Keep the DP and DM traces as short as possible.

- Route the DP and DM signals with a minimum amount of corners. Use 45-degree turns instead of 90-degree turns.
- Avoid layer changes (vias) on the DP and DM signals. Do not create stubs or branches.
- Provide the ground return vias within a 50-mil distance from the signal layer-transition vias when transitioning between different reference ground planes.

7.5. High-speed signal routing recommendations

The following list provides recommendations for routing the traces for high-speed signals. Note that the propagation delay and the impedance control must match to have a correct communication with the devices.

- The high-speed signals (SDRAM, RMII, Display, Hyperflash, SD card) must not cross gaps in the reference plane.
- Avoid creating slots, voids, and splits in the reference planes. Review the via voids to ensure that they do not create splits (space out vias).
- Provide the ground return vias within a 100-mil distance from the signal layer-transition vias when transitioning between different reference ground planes.
- A solid GND plane must be directly under the crystal-associated components, and traces.
- The clocks or strobes that are on the same layer need at least 2.5× spacing from the adjacent traces (2.5× height from the reference plane) to reduce crosstalk.
- Provide the ground return vias within a 100-mil distance from the signal layer-transition vias when transitioning between different reference ground planes.
- All synchronous modules must have the bus length matching and relative clock length control.
- For the SD module interfaces:
 - Match the data, clock, and CMD trace lengths (length delta depends on the bus rates).
 - Follow similar SDRAM rules for data, address, and control as for the SD module interfaces.

8. Revision history

Table 12 summarizes the changes done to this document since the initial release.

Table 12. Revision history

Revision number	Date	Substantive changes
0	10/2017	Initial release
1	11/2017	Changed TO1.0 and TO1.1 to silicon A0 and A1.

How to Reach Us:

Home Page: nxp.com

Web Support:

nxp.com/support

Information in this document is provided solely to enable system and software implementers to use NXP products. There are no express or implied copyright licenses granted hereunder to design or fabricate any integrated circuits based on the information in this document. NXP reserves the right to make changes without further notice to any products herein.

NXP makes no warranty, representation, or guarantee regarding the suitability of its products for any particular purpose, nor does NXP assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters that may be provided in NXP data sheets and/or specifications can and do vary in different applications, and actual performance may vary over time. All operating parameters, including "typicals," must be validated for each customer application by customer's technical experts. NXP does not convey any license under its patent rights nor the rights of others. NXP sells products pursuant to standard terms and conditions of sale, which can be found at the following address:

nxp.com/SalesTermsandConditions.

NXP, the NXP logo, NXP SECURE CONNECTIONS FOR A SMARTER WORLD, Freescale, and the Freescale logo are trademarks of NXP B.V. All other product or service names are the property of their respective owners.

Arm, the Arm Powered logo, and Cortex are registered trademarks of Arm Limited (or its subsidiaries) in the EU and/or elsewhere. All rights reserved.

© 2017 NXP B.V.

Document Number: MIMXRT1050HDUG Rev.1 11/2017



